# SENSITRON SEMICONDUCTOR

TECHNICAL DATA DATA SHEET 4756, REV. A

# POWER SCHOTTKY RECTIFIER Very Low Reverse Leakage

## **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

## Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	60	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle, rectangular	120	A
Current		wave form		
Max. Peak One Cycle Non-	I <sub>FSM</sub>	8.3 ms, half Sine wave	1650	А
Repetitive Surge Current		(per leg)		
Non-Repetitive Avalanche	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.3 A,	27	mJ
Energy		L = 40 mH (per leg)		
Repetitive Avalanche	I <sub>AR</sub>	$I_{AS}$ decay linearly to 0 in 1 $\mu$ s	1.3	А
Current		f limited by $T_J \max V_A = 1.5 V_B$		
Thermal Resistance	R <sub>thJC</sub>	Per Package	0.2	°C/W
Max. Junction Temperature	ΤJ	-	-65 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +150	°C

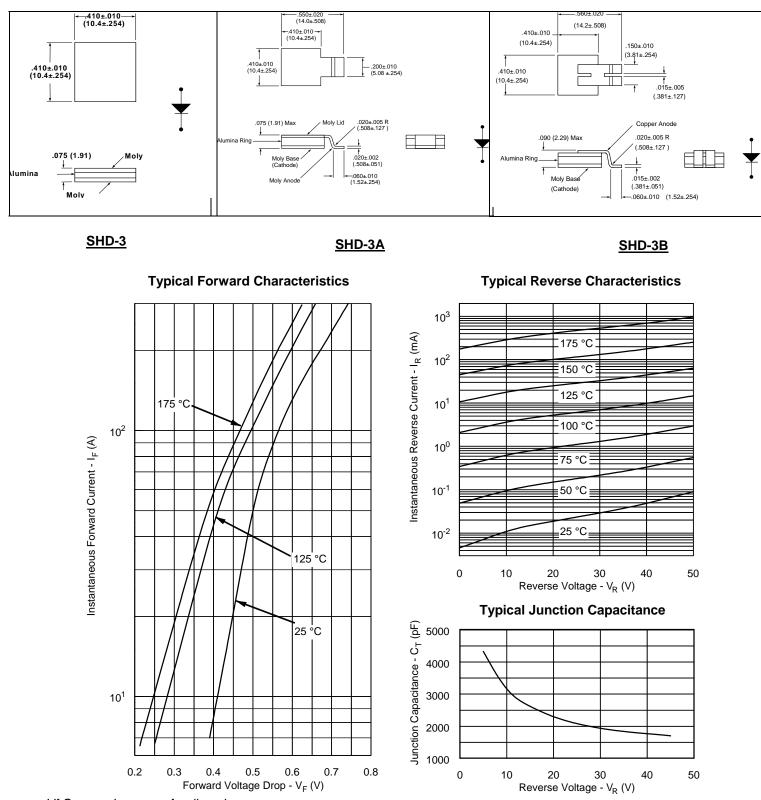
## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 120A, Pulse, $T_J = 25 \text{ °C}$ (per leg) measured at the leads	0.70	V
	V <sub>F2</sub>	@ 120A, Pulse, $T_J = 125 \text{ °C}$ (per leg) measured at the leads	0.67	V
Max. Reverse Current	I <sub>R1</sub>	$@V_R = 60V$ , Pulse, T <sub>J</sub> = 25 °C (per leg)	11	mA
	I <sub>R2</sub>	$@V_R = 60V$ , Pulse, T <sub>J</sub> = 125 °C (per leg)	840	mA
Max. Junction Capacitance	C <sub>T</sub>	$@V_R = 5 V, T_C = 25 °C$ $f_{SIG} = 1 MHz,$ $V_{SIG} = 50mV (p-p) (per leg)$	4800	pF

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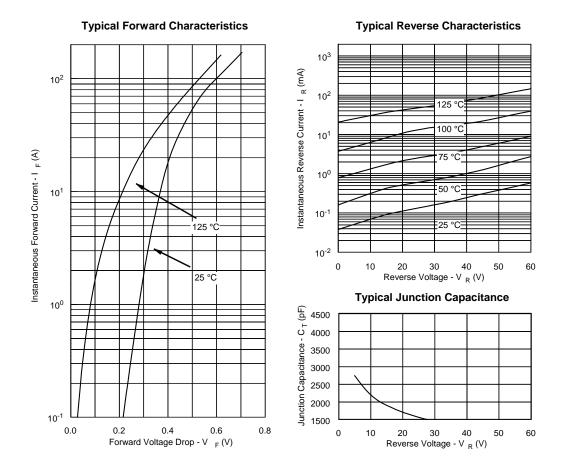
Mechanical Dimensions: in inches / mm



Vf Curves shown are for die only.

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